HOPPLUS, INSTERO, TAPSO, US PATALL)

=> d 113 abs,bib

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L13 ANSWER 1 OF 1 USPATFULL on STN
           The present invention relates to silicon feedstock
           for producing directionally solidified
           silicon ingots, thin sheets and ribbons for
           the production of silicon wafers for PV solar cells where the
           silicon feedstock contains between 0.2 and 10 ppma
          boron and between 0.1 and 10 ppma phosphorus distributed in the
           material. The invention further relates to directionally
          material. The invention further relates to directionally solidified silicon ingot or thin silicon sheet or ribbon for making wafers for solar cells containing between 0.2 ppma and 10 ppma boron and between 0.1 ppma and 10 ppma phosphorus distributed in the ingot, said silicon ingot having a type change from p-type to n-type or from n-type to p-type at a position between 40 and 99% of the ingot height or sheet or ribbon thickness and having a resistivity profile describes by an exponential curve having a starting value between 0.4 and 10 ohm om and where the resistivity value increases towards the type change point. Finally the invention relates to a method for producing silicon feedstock for producing directionally solidified silicon ingots thin sheets and ribbons for the production of silicon wafers for PV solar cells.
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
ΑN
           2007:147006 USPATFULL
           Silicon feedstock for solar cells
ΤI
TN
           Enebakk, Erik, Kristiansand, NORWAY
           Friestad, Kenneth, Kristiansand, NORWAY
          Tronstad, Ragnar, Sogne, NORWAY
          Zahedi, Cyrus, Sandvika, NORWAY
          Dethloff, Christian, Oslo, NORWAY
PA
          ELKEM ASA, Oslo, NORWAY, 0377 (non-U.S. corporation)
PΙ
          US 2007128099 ,
                                    A1 20070607
          US 2004-585004
                                        A1
                                              20040112 (10)
          WO 2004-NO3
                                              20040112
                                              20060628 PCT 371 date
PRAI
          NO 2003-5830
                                        20031229
          Utility
FS
          APPLICATION
LREP
          LUCAS & MERCANTI, LLP, 475 PARK AVENUE SOUTH, 15TH FLOOR, NEW YORK, NY,
          10016, US
          Number of Claims: 9
CLMN
\mathsf{ECL}
          Exemplary Claim: 1
          1 Drawing Page(s)
LN.CNT 297
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
=> d his
       (FILE 'HOME' ENTERED AT 16:24:13 ON 07 NOV 2007)
       FILE 'ABI-INFORM, INSPEC, JAPIO, USPATFULL, USPATOLD, USPAT2' ENTERED AT
       16:24:49 ON 07 NOV 2007
                  560 S (SI OR SILICON) (8A) (FEEDSTOCK)
L1
L2
              12708 S (FZ OR FLOAT (2W) ZONE)
L3
                     0 S (MULTICRYSTAL? RO POLYCRYSTAL?) (8A) (INGOT# OR BOULE# OR CRYST
L4
              17150 S (SOLIDIF?(10A)DIRECT?)
L5
              38650 S (CZ OR CZOCHRALSKI)
              59572 S (SHEET# AND RIBBON#)
L6
L7
             154055 S (SI OR SILICON) (8A) (WAFER#)
r_8
                  622 S (PV(6A)SOLAR(3W)CELL#)
           5600997 S (B OR BORON)
L9
```

L10	3525187	S	(P	OR	PHOS	SPHO	RUS)							
L11	1	S	L1	AND	L2	AND	L4	AND	L5	AND	L6	AND	L9	AND	L10
L12								AND							
L13	1	S	L1	AND	L2	AND	L4	AND	L5	AND	L6				

=> d his

(FILE 'HOME' ENTERED AT 16:24:13 ON 07 NOV 2007)

FILE 'ABI-INFORM, INSPEC, JAPIO, USPATFULL, USPATOLD, USPAT2' ENTERED AT 16:24:49 ON 07 NOV 2007 L1560 S (SI OR SILICON) (8A) (FEEDSTOCK) 12708 S (FZ OR FLOAT (2W) ZONE) L2L3 0 S (MULTICRYSTAL? RO POLYCRYSTAL?) (8A) (INGOT# OR BOULE# OR CRYST 17150 S (SOLIDIF?(10A)DIRECT?) L438650 S (CZ OR CZOCHRALSKI) L5L6 59572 S (SHEET# AND RIBBON#) L7 154055 S (SI OR SILICON) (8A) (WAFER#) T8 622 S (PV(6A)SOLAR(3W)CELL#) L9 5600997 S (B OR BORON) L10 3525187 S (P OR PHOSPHORUS) \Rightarrow s 11 and 12 and 14 and 15 and 16 and 19 and 110 L111 L1 AND L2 AND L4 AND L5 AND L6 AND L9 AND L10

=> d 11 abs,bib

- L1ANSWER 1 OF 560 ABI/INFORM COPYRIGHT 2007 ProQuest Information and Learning Company; All Rights Reserved on STN
- The photovoltaic industry has been growing with astonishing rates over the AB past years. The supply of silicon to the wafer-based industry has recently become a problem. This paper presents a thorough analysis of the PV industry and quantifies the silicon shortage. It is expected that this leads to a decrease in production in 2006 rather than the usual increase. Due to a mismatch in expansion plans of silicon feedstock manufacturers and solar cell manufacturers, a large cell overcapacity will persist up to 2010. The thin-film PV market is expected to profit from the silicon shortage problem; its market share may substantially increase to about 25% in 2010. [PUBLICATION ABSTRACT] ΑN

2007:63604 ABI-INFORM

DN 1258159731

ΤI Analysis of the silicon market: Will thin films profit?

ΑU Brandsen, G W; Fleuster, M; Hekkert, M P

Energy Policy: Publisher: Kidlington, (2007) Vol. 35, No. 6, p. 3121. SO Journal code: ENP; 17184. AVAILABILITY: NO CODEN: ENPYAC; ISSN: 0301-4215.

DΤ JOURNAL

- TC PERIODICAL
- LA English

ED Entered STN: 1 Jun 2007 Last Updated on STN: 1 Jun 2007

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Donald Chucas TELH(34) 66/-8000 Fay A(3) 66/-8002

14/585, QAH

Examiner's Notes

M 903 (03/08/2007)

X Rod U.S. Pat No. 4, 247, 5 HA (Dasay, etal) Crains 2-6 89

Helected Poduct Clains 1-8 in 10/3/2007,

S(Si or silicon) (10a) (feeds tock) S(FZ or float (u) zone)

S(solidif?) [100] (direction?) or (solidif? (Ba) direct?)

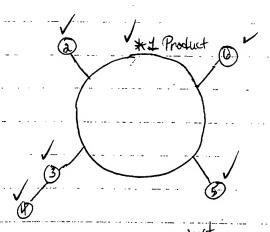
S(CZ or czochralski) S(Sheet# and ribbon#)

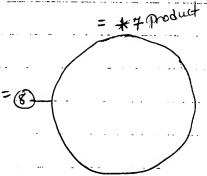
S (Si or silicen) (80) (water#) S (DV (la) solar (2w) ceil#)

s (B or becom) S (Por phosphorus)

18/149,176

12/722,813





Clarus 1-4 over U.S. Patt 4,247,508A

112Pa Ke .. characterized in that ... "

Allowable Sebi Matter Claims 768

Analysis of the Silicon warter: Will thin Silles probit?

Brandsen G. W; Flewster, H; HeKKert, MP.

Energy Policy : Publisher: Kid lington, Soot, Vol. 35, No. 6, p. 3/21.
ISSN: 0384-4225